



ZVP4525E6

### 250V P-CHANNEL ENHANCEMENT MODE MOSFET

### **Product Summary**

V <sub>(BR)DSS</sub>	R <sub>DS(ON)</sub> max	I <sub>D</sub> max T <sub>A</sub> = +25℃
-250V	14Ω @ V <sub>GS</sub> = -10V	-197mA
-250V	18Ω @ V <sub>GS</sub> = -3.5V	-175mA

### **Description**

This 250V enhancement mode P-channel MOSFET provides users with a competitive specification. It offers efficient power handling capability, high impedance and is free from thermal runaway and thermally induced secondary breakdown. Applications benefiting from this device include a variety of Telecom and general high voltage circuits.

SOT89 and SOT223 versions are also available.

### **Applications**

- Earth Recall and Dialing Switches
- Electronic Hook Switches
- High Voltage Power MOSFET Drivers
- Telecom Call Routers
- Solid State Relays

# Features and Benefits

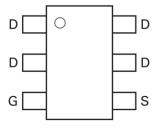
- High voltage
- Low on-resistance
- Fast switching speed
- Low gate drive
- Low threshold
- Complementary N-channel Type ZVN4525E6
- SOT23-6 package
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

### **Mechanical Data**

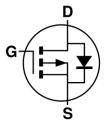
- Case: SOT26
- Case Material: Molded Plastic.
  UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Annealed over Copper Leadframe.
  Solderable per MIL-STD-202, Method 208 3
- Weight 0.018 grams (Approximate)







Top View Pin-Out



**Equivalent Circuit** 

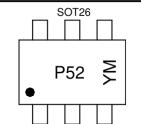
### Ordering Information (Note 4)

Part Number	Case	Quantity per reel
ZVP4525E6TA	SOT26	3,000
ZVP4525E6TC	SOT26	3,000

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- 2. See http://www.diodes.com/quality/lead\_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

### **Marking Information**



P52 = Product Type Marking Code YM = Date Code Marking Y or  $\overline{Y}$  = Year (ex: C = 2015) M or  $\overline{M}$  = Month (ex: 9 = September)

Date Code Key

Year	2015	2016	2017	2018	2019	2020	2021	2022
Code	С	D	E	F	G	Н	I	J

Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	N	D



## **Maximum Ratings** (@ $T_A = +25$ °C, unless otherwise specified.)

C	haracteristic		Symbol	Value	Unit
Drain-Source Voltage			$V_{DSS}$	-250	V
Gate-Source Voltage			V <sub>GS</sub>	±40	V
O tier	10)/	(Note 5)	ΙD	-197	·~ Λ
Continuous Drain Current	$V_{GS} = 10V$	$T_A = +70$ °C (Note 5)		-157	mA
Pulsed Drain Current	V <sub>GS</sub> = 10V	(Note 7)	I <sub>DM</sub>	-1	Α
Continuous Source Current (	Body Diode)		Is	-0.75	Α
Pulsed Source Current (Body	y Diode)		I <sub>SM</sub>	-1	Α

### Thermal Characteristics (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Power Dissipation	(Note 5)	D	1.1	W
Linear Derating Factor	(Note 5)	$P_{D}$	8.8	mW/℃
Thermal Desistance, Investigate Amphicat	(Note 5)	5	113	90.44
Thermal Resistance, Junction to Ambient	(Note 6)	$R_{\theta JA}$	68	°C/W
Operating and Storage Temperature Range	T <sub>J</sub> , T <sub>STG</sub>	-55 to +150	∞	

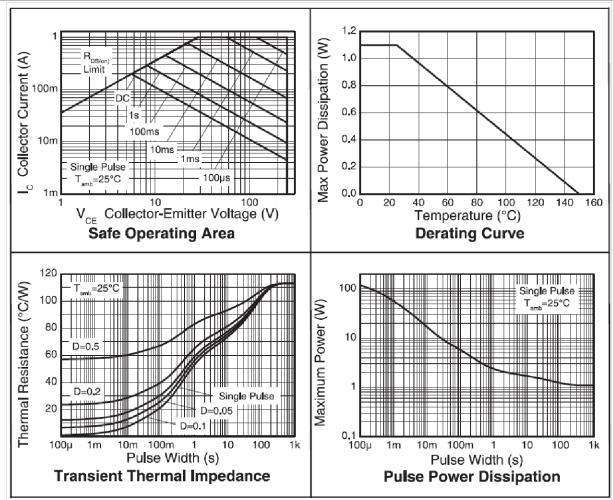
Notes:

- 5. For a device surface mounted on 25mm x 25mm x 1.6mm FR4 PCB with high coverage of single sided 1oz copper, in still air conditions; the device is measured when operating in a steady-state condition.
- 6. For a device surface mounted on FR4 PCB measured at  $t \le 5$  secs.
- 7. Repetitive rating pulse width limited by maximum junction temperature. Refer to Transient Thermal Impedance graph.

#### **NB High Voltage Applications**

For high voltage applications, the appropriate industry sector guidelines should be considered with regard to voltage spacing between conductors.

### Thermal Characteristics





# Electrical Characteristics (@T<sub>A</sub> = +25 °C, unless otherwise specified.)

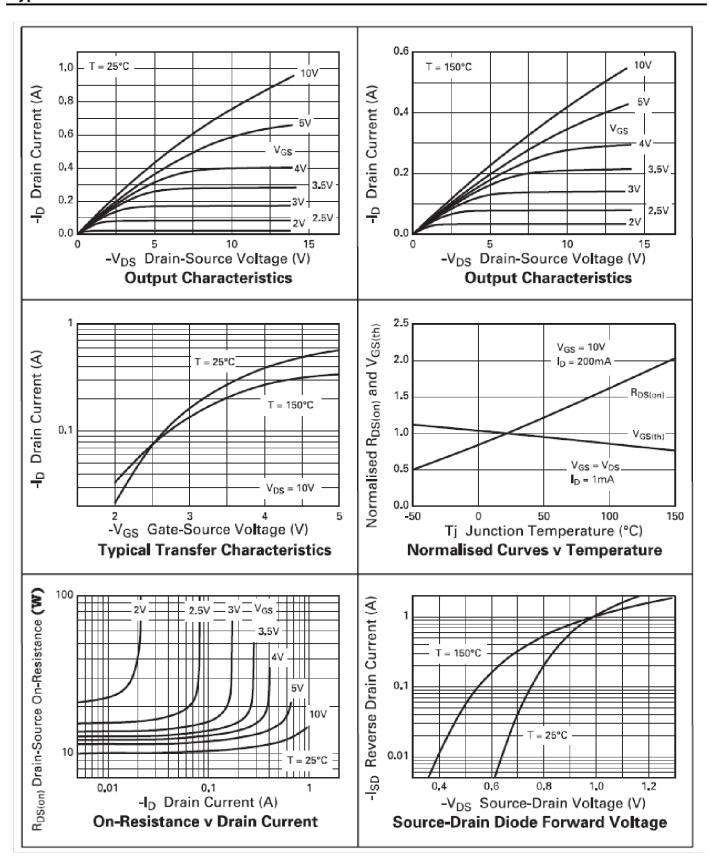
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS							
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	-250	-285	_	V	$I_D = -1 \text{mA}, V_{GS} = 0 \text{V}$	
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	_	-30	-500	nA	V <sub>DS</sub> = -250V, V <sub>GS</sub> = 0V	
Gate-Source Leakage	I <sub>GSS</sub>	_	±1	±100	nA	$V_{GS} = \pm 40V, V_{DS} = 0V$	
ON CHARACTERISTICS					•	,	
Gate Threshold Voltage	V <sub>GS(th)</sub>	-0.8	-1.5	-2.0	V	$I_D = -1 \text{mA}, V_{DS} = V_{GS}$	
Otatia Dunin Carres On Basistana (Nata O)		_	10	14		V <sub>GS</sub> = -10V, I <sub>D</sub> = -200mA	
Static Drain-Source On-Resistance (Note 8)	R <sub>DS(ON)</sub>	_	13	18	Ω	V <sub>GS</sub> = -3.5V, I <sub>D</sub> = -100mA	
Forward Transconductance (Notes 10)		80	200	_	mS	V <sub>DS</sub> = -10V, I <sub>D</sub> = -0.15A	
Diode Forward Voltage (Note 9)	V <sub>SD</sub>	_	-0.86	-0.97	V	$I_S = -200 \text{mA}, V_{GS} = 0 \text{V},$ $T_J = +25 ^{\circ}\text{C}$	
DYNAMIC CHARACTERISTICS (Note 10)						•	
Input Capacitance	C <sub>iss</sub>	_	73	_			
Output Capacitance	Coss	_	12.8	_	рF	$V_{DS} = -25V, V_{GS} = 0V$ f = 1MHz	
Reverse Transfer Capacitance	C <sub>rss</sub>	_	3.91	_		I = IIVITZ	
Total Gate Charge (Note 9)	Qg	_	2.45	2.45		V <sub>DS</sub> = -25V, V <sub>GS</sub> = -10V,	
Gate-Source Charge (Note 9)	Q <sub>gs</sub>	_	0.22	0.31	nC	I <sub>D</sub> = -200mA (refer to	
Gate-Drain Charge (Note 9)	Q <sub>gd</sub>	_	0.45	0.63		test circuit)	
Turn-On Delay Time (Note 9)	t <sub>D(on)</sub>	_	1.53	_			
Turn-On Rise Time (Note 9)	t <sub>r</sub>	_	3.78	_	]	$V_{DD} = -30V, V_{GS} = -10V$	
Turn-Off Delay Time (Note 9)	t <sub>D(off)</sub>	_	17.5	_	ns	$I_D$ = -200mA, $R_G$ = 50Ω (refer to test circuit)	
Turn-Off Fall Time (Note 9)	t <sub>f</sub>	_	7.85	_	1	lost on out.)	
Reverse Recovery Time	t <sub>rr</sub>	_	205	290	ns	$I_F = -200 \text{mA},  \text{di/dt} = 100 \text{A/} \mu \text{s},$	
Reverse Recovery Charge	Q <sub>rr</sub>		21	29	nC	T <sub>J</sub> = +25℃	

Notes:

- 8. Measured under pulsed conditions. Width  $\leq 300 \mu s.$  Duty cycle  $\leq 2\%.$
- Switching characteristics are independent of operating junction temperatures.
  For design aid only, not subject to production testing.

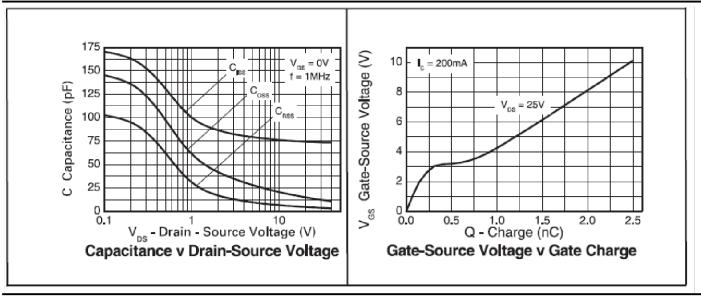


### **Typical Characteristics**

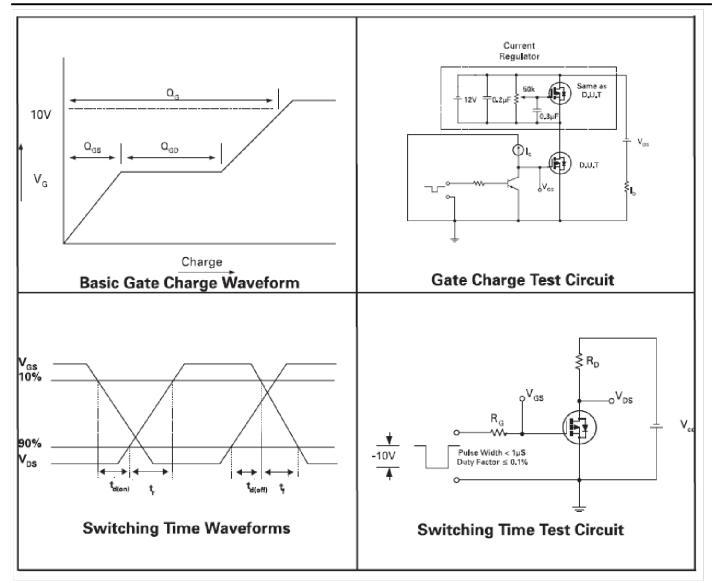




### Typical Characteristics (continued)



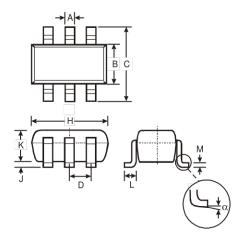
## **Test Circuits**





## **Package Outline Dimensions**

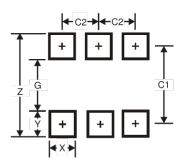
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for the latest version.



	SOT26								
Dim	Min	Max	Тур						
Α	0.35	0.50	0.38						
В	1.50	1.70	1.60						
С	2.70	3.00	2.80						
D	_	_	0.95						
Н	2.90	3.10	3.00						
J	<b>J</b> 0.013		0.05						
K	1.00	1.30	1.10						
L	0.35	0.55	0.40						
M	<b>M</b> 0.10		0.15						
α	0°	8°	_						
All D	All Dimensions in mm								

## **Suggested Pad Layout**

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)
Z	3.20
G	1.60
X	0.55
Y	0.80
C1	2.40
C2	0.95



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